



CPH5517 — PNP/NPN Epitaxial Planar Silicon Transistors

High-Current Switching Applications

Applications

- relay drivers, lamp drivers, motor drivers

Features

- Composite type with a PNP/NPN transistor contained in package, facilitating high-density mounting
- The CPH5517 consists of two chips which are equivalent to the CPH3116 and the CPH3216, respectively
- Ultrasmall package permitting applied sets to be small and slim (mounting height : 0.9mm)

Specifications () : PNP

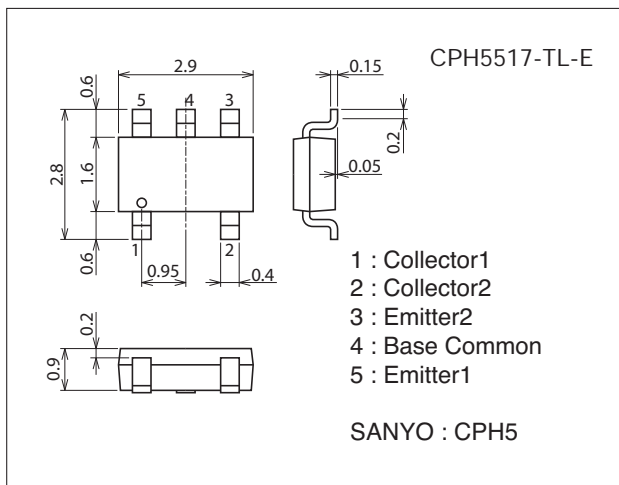
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		(-50)60	V
Collector-to-Emitter Voltage	V _{CEO}		(-50)	V
Emitter-to-Base Voltage	V _{EB0}		(-5)	V
Collector Current	I _C		(-1.0)	A
Collector Current (Pulse)	I _{CP}		(-3)	A
Base Current	I _B		(-200)	mA
Collector Dissipation	P _C	Mounted on a ceramic board (600mm ² ×0.8mm) 1unit	0.9	W
Junction Temperature	T _j		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Package Dimensions

unit : mm (typ)

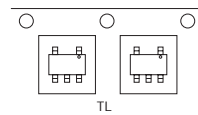
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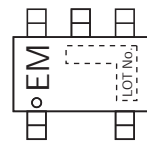
Product & Package Information

- Package : CPH5
- JEITA, JEDEC : SC-74A, SOT-25
- Minimum Packing Quantity : 3,000 pcs./reel

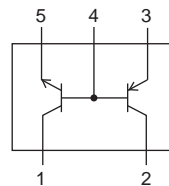
Packing Type : TL



Marking



Electrical Connection

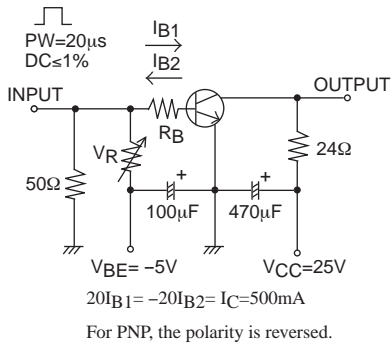


CPH5517

Electrical Characteristics at Ta=25°C

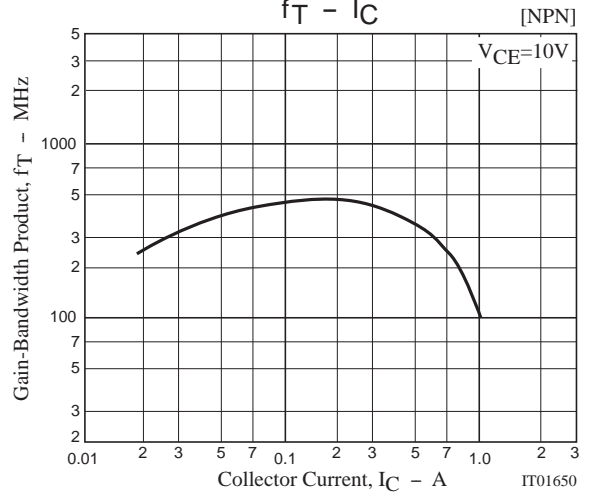
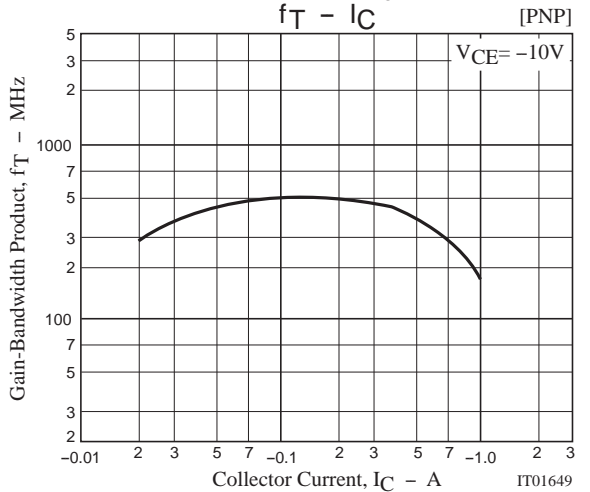
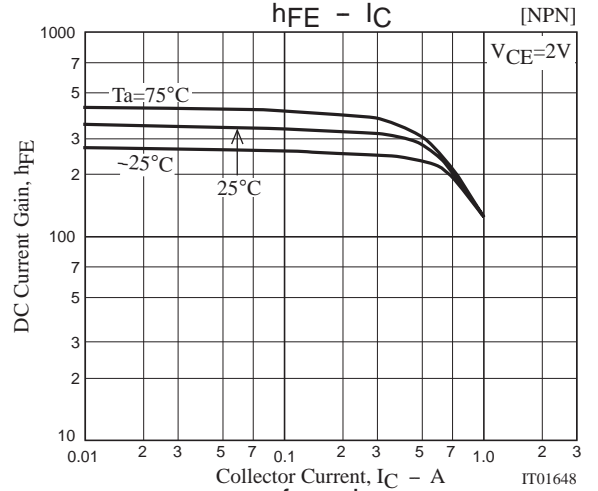
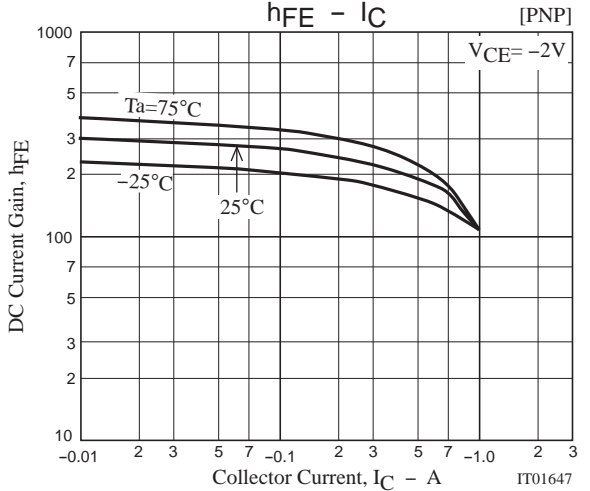
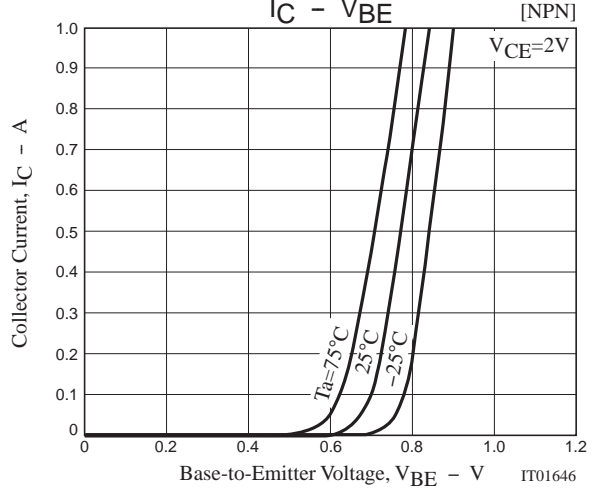
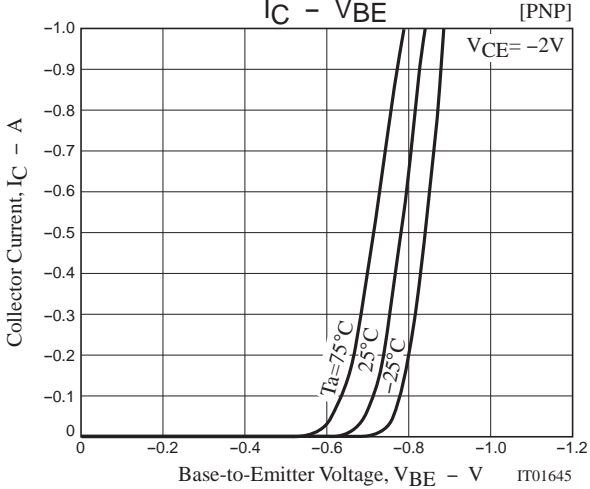
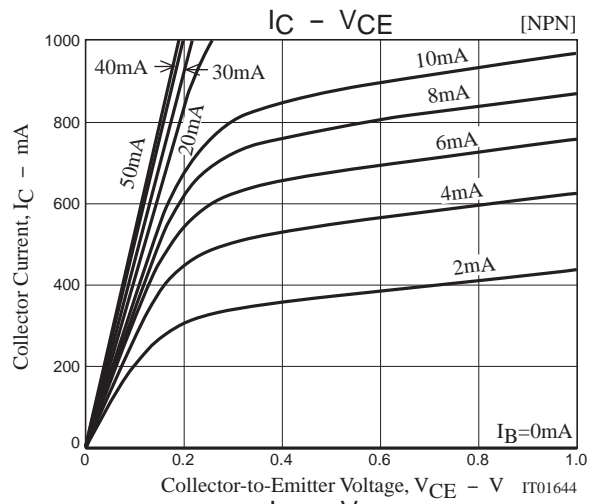
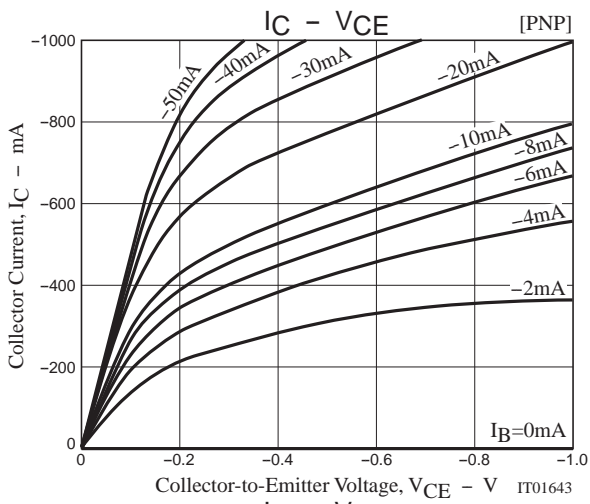
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)40V, I_E=0A$			(-)0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4V, I_C=0A$			(-)0.1	μA
DC Current Gain	h_{FE}	$V_{CE}=(-)2V, I_C=(-)100mA$	200		560	
Gain-Bandwidth Product	f_T	$V_{CE}=(-)10V, I_C=(-)300mA$		420		MHz
Output Capacitance	Cob	$V_{CB}=(-)10V, f=1MHz$		(9)6		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)500mA, I_B=(-)10mA$		(-280)	(-430)	mV
		$I_C=(-)300mA, I_B=(-)6mA$		130	190	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)500mA, I_B=(-)10mA$		(-)0.81	(-)1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0A$	(-50)60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-)50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0A$	(-)5			V
Turn-On Time	t_{on}	See specified Test Circuit.		(36)38		ns
Storage Time	t_{stg}			(173)332		ns
Fall Time	t_f			(28)40		ns

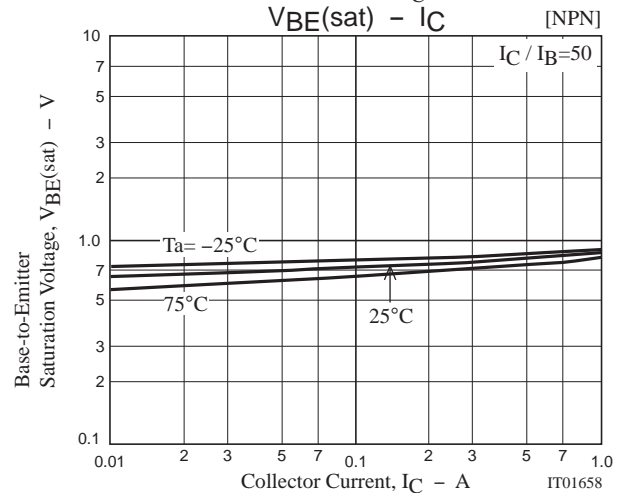
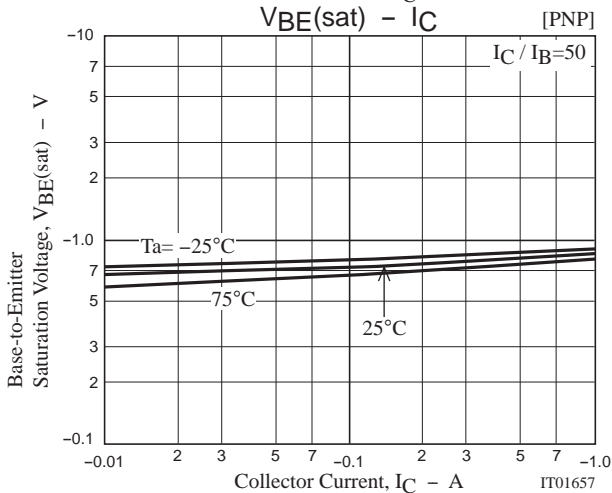
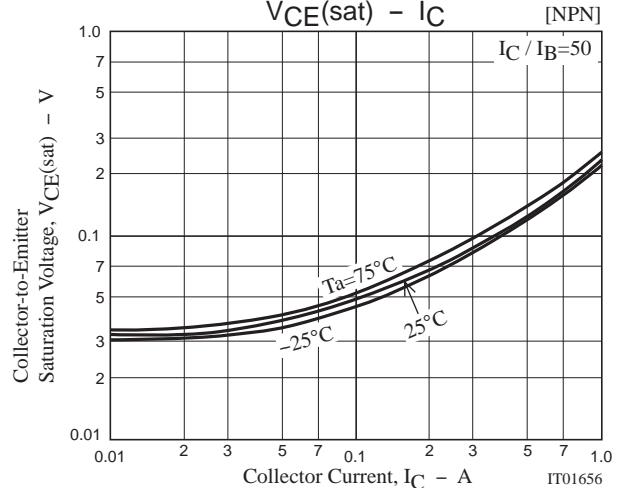
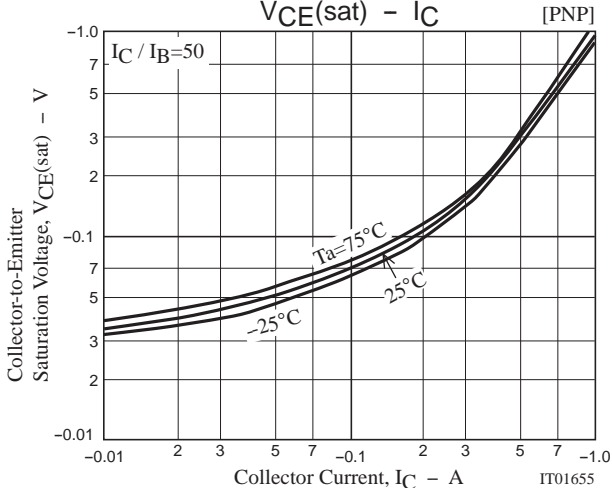
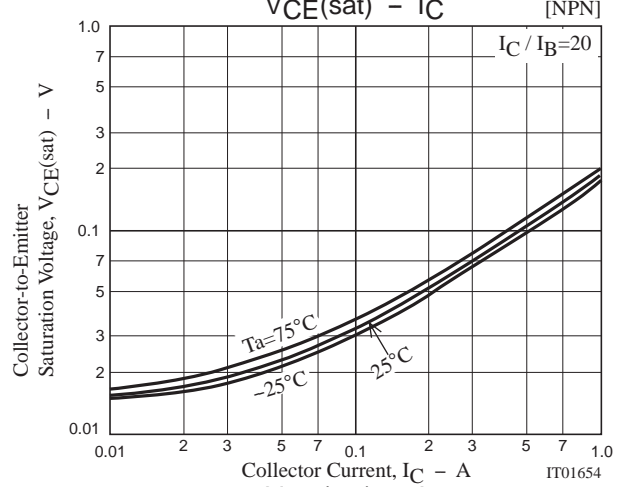
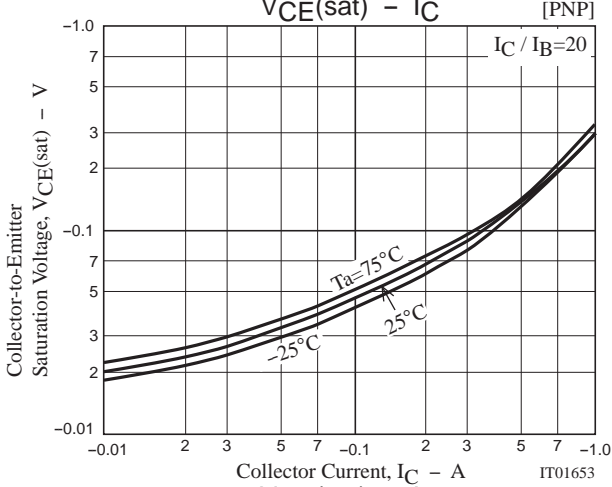
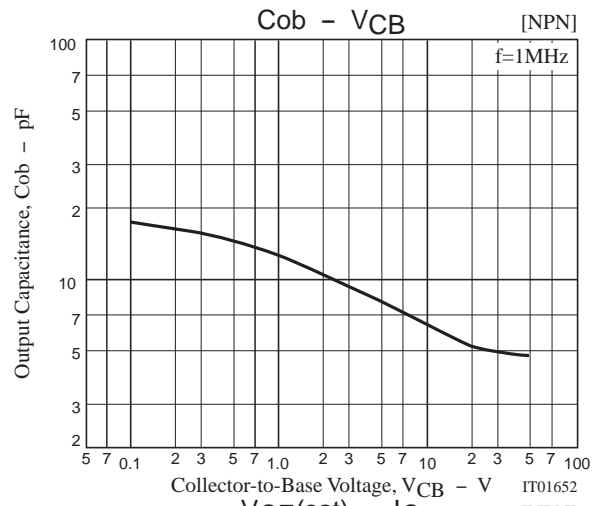
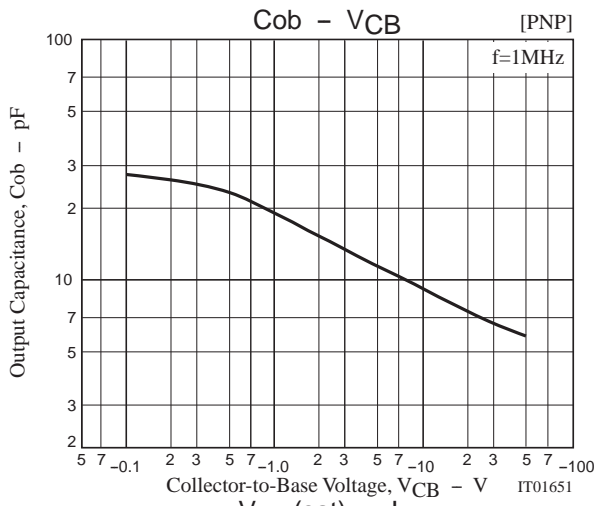
Switching Time Test Circuit

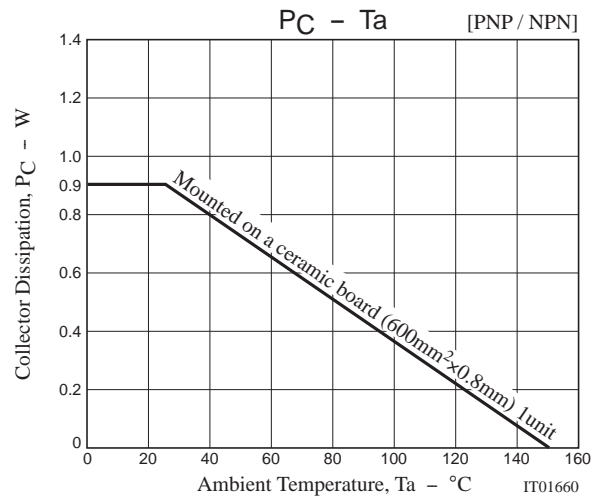
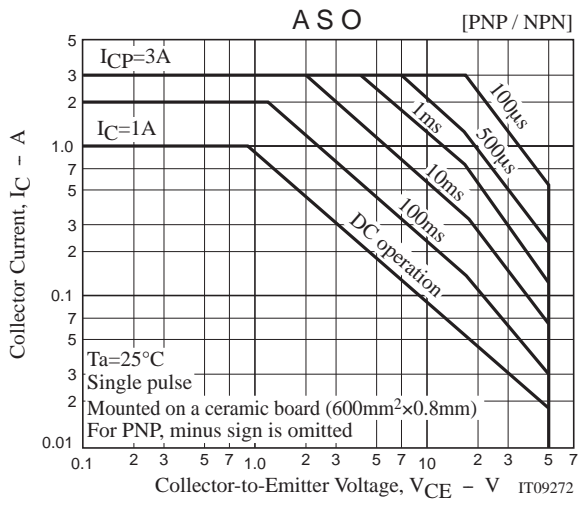


Ordering Information

Device	Package	Shipping	memo
CPH5517-TL-E	CPH5	3,000pcs./reel	Pb Free







Embossed Taping Specification

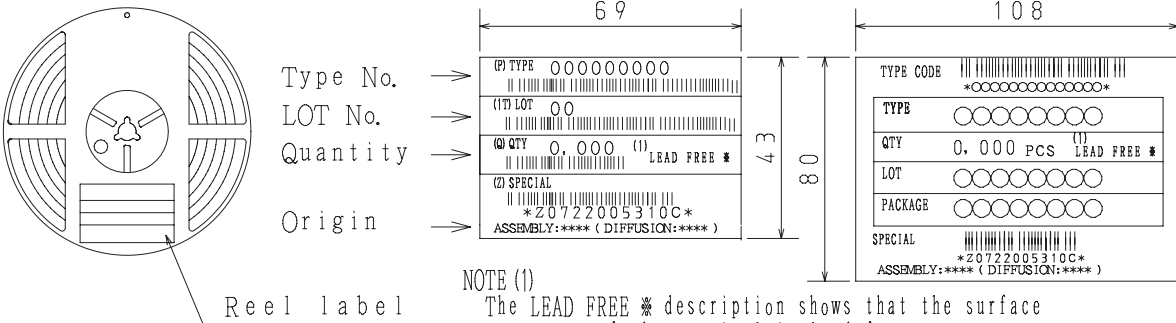
CPH5517-TL-E

1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
CPH5	CPH6	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method

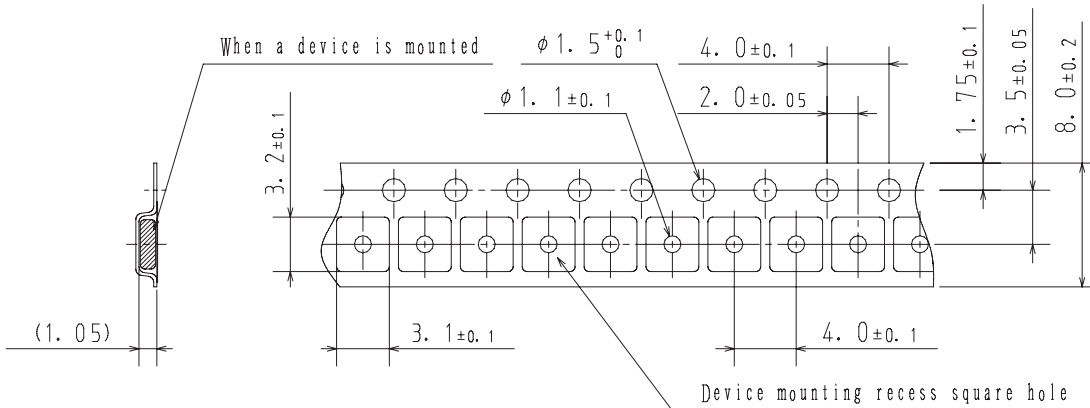
Reel label, Inner box label (unit:mm) Outer box label
 [It is a label at the time of factory shipments. The form of a label may change in physical distribution process.]



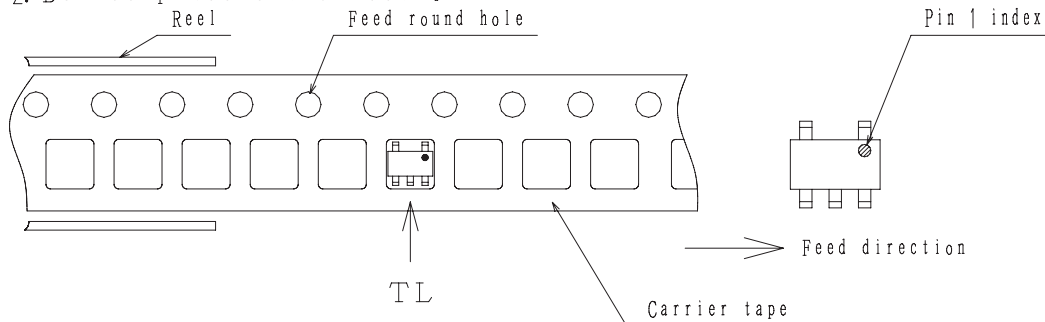
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



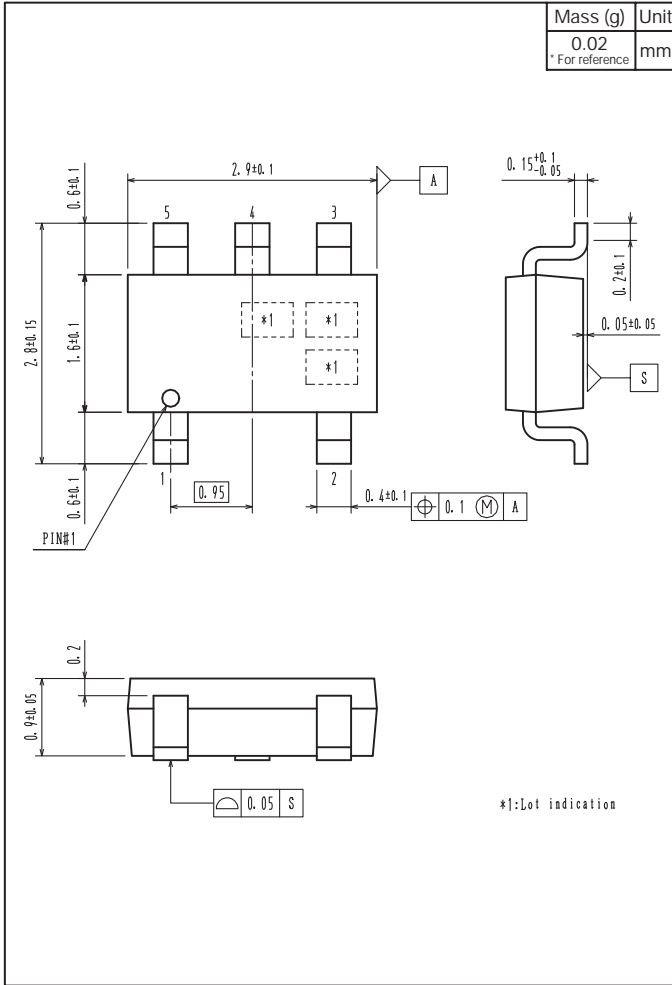
2-2. Device placement direction



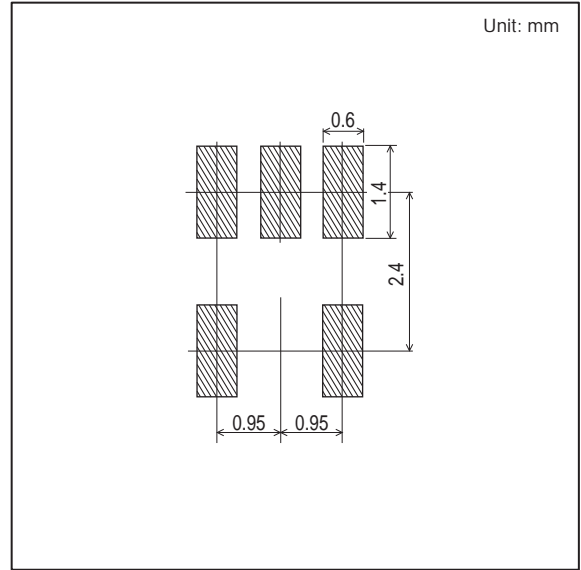
Those with pin 1 index on the feed hole side.....TL

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Outline Drawing CPH5517-TL-E



Land Pattern Example



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